Amendments to the Claims:

This listing of claims replaces all prior versions and listings of claims in the application:

Listing of Claims:

- 1. (Original) An OLED device comprising a light-emitting layer containing a host and a dopant where the dopant comprises a boron compound containing a bis(azinyl)methene boron complex group.
- 2. (Original) The device of claim 1 wherein the layer comprises a host and dopant where the dopant is present in an amount of up to 10 wt % of the host.
- 3. (Original) The device of claim 2 wherein the dopant is present in an amount of 0.1-5.0 wt % of the host.
- 4. (Original) The device of claim 1 wherein the boron complex group is a 6,6,6-tricyclic bis(azinyl)methene boron complex group.
- 5. (Original) The device of claim 4 wherein the boron complex group is a bis(pyridinyl)methene boron complex group.
- 6. (Original) The device of claim 5 wherein at least one of the pyridyl groups is substituted.
- 7. (Original) The device of claim 6 wherein at least one of the pyridyl groups has substituent groups joined to form a fused ring.
- 8. (Original) The device of claim 1 wherein the host comprises a chelated oxinoid compound or an anthracene compound.
- 9. (Original) The device of claim 8 wherein the host comprises a chelated oxinoid compound.
- 10. (Original) The device of claim 8 wherein the host comprises an anthracene compound.

- 11. (Original) The device of claim 1 wherein the host comprises tris(8-quinolinolato)aluminum (III) or 2-tert-butyl-9,10-di-(2-naphthyl)anthracene.
- 12. (Currently amended) The device of claim 1 wherein the substituents of the host and dopant are selected to provide an emitted light having a green hue.
- 13. (Currently amended) The device of claim 1 wherein the substituents of the host and dopant are selected to provide a reduced loss of initial luminance compared to the device containing no boron compound of claim 1.
- 14. (Original) The device of claim 1 wherein the dopant compound is represented by Formula (1):

$$(1) \qquad (X^{a})_{m} \stackrel{\text{ll}}{=} A \qquad A' \stackrel{\text{l}}{=} A' \stackrel{\text{l}}{=} (X^{b})_{n}$$

$$Z^{a'} Z^{b} \qquad (X^{b})_{n} \qquad (X^{b})$$

wherein

A and A' represent independent azine ring systems corresponding to 6membered aromatic ring systems containing at least one nitrogen;

each X^a and X^b is an independently selected substituent, two of which may join to form a fused ring to A or A';

m and n are independently 0 to 4;

Y is H or a substituent;

Z^a and Z^b are independently selected substituents:

- 1, 2, 3, 4, 1', 2', 3', and 4' are independently selected as either carbon or nitrogen atoms.
- 15. (Original) The device of claim 14 wherein 1, 2, 3, 4, 1', 2', 3', and 4' are all carbon atoms.
- 16. (Original) The device of claim 14 wherein at least one of ring A or A' contains substituents joined to form a fused ring.
- 17. (Original) The device of claim 14 wherein both ring A and A' contain substituents joined to form a fused ring.

- 18. (Currently amended) The device of claim 14 wherein there is present at least one X^a or X^b group selected from the group consisting of halide, and alkyl, aryl, alkoxy, and aryloxy groups.
- 19. (Currently amended) The device of claim 14 wherein Z^a and Z^b are independently selected from the group consisting of fluorine, and alkyl, aryl, alkoxy and aryloxy groups.
 - 20. (Original) The device of claim 19 wherein Z^a and Z^b are F.
- 21. (Original) The device of claim 14 wherein the layer comprises a host and dopant where the dopant is present in an amount of up to 10 wt % of the host.
- 22. (Original) The device of claim 21 wherein the dopant is present in an amount of 0.1-5.0 wt % of the host.
- 23. (Original) The device of claim 1 wherein the boron compound is selected from the following.

Inv-6

Inv-7

Inv-8

Inv-9

Inv-10

Inv-11

Inv-13

Inv-14

Inv-15

Inv-16

Inv-17

Inv-18

Inv-20

Inv-21

Inv-22

Inv-23

Inv-24

Inv-25

24. (Original) The device of claim 1 wherein the boron compound is selected from the following.

- Inv-1

 Inv-4

 Inv-5
- 25. (Original) A light emitting device containing the OLED device of claim 1.
- 26. (Original) A method of emitting light comprising subjecting the device of claim 1 to an applied voltage.